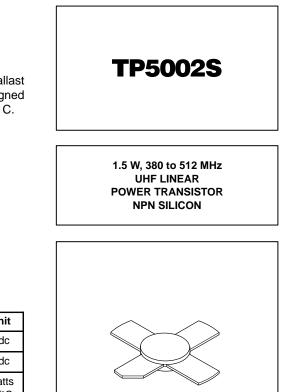
The RF Line **UHF Linear Power Transistor**

The TP5002S is an NPN gold metallized transistor using diffused ballast resistors for reliability and ruggedness. The TP5002S was specifically designed as a low power driver with high gain and can be operated in Class A, B or C.

- 380-512 MHz
- 1.5 W Pout
- 24 V VCC
- High Gain 13 dB Min, Class A @ 470 MHz

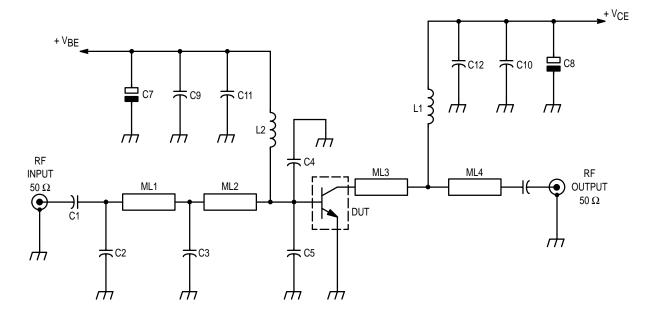


MAXIMUM RATINGS

Rating	Symbol	Symbol Value		Unit		\frown	$\langle \rangle$		
Collector-Base Voltage	VCBO	45		Vdc	1		\sim		
Emitter-Base Voltage	VEBO	3.5		Vdc	1				
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	7.0 0.045		Watts W/°C					
Operating Junction Temperature	Тј	200		°C					
Storage Temperature Range	T _{stg}	-65 to +200		°C					
THERMAL CHARACTERISTICS					-				
Characteristic	Symbol	Max		Unit		CASE 249–06, STYLE 1			
Thermal Resistance, Junction to Case (T _C = 70°C)	R _{θJC}	21		°C/W		(.280 SOE S)			
ELECTRICAL CHARACTERISTICS $(T_{C}$	= 25°C unless	s otherwis	e noted	.)					
Characteristic			Syr	nbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS									
Collector–Base Breakdown Voltage $(I_{C} = 2.0 \text{ mA}, I_{E} = 0)$			V _(BR) CBO		45	-	-	Vdc	
Emitter–Base Breakdown Voltage $(I_E = 2.0 \text{ mA}, I_C = 0)$			V _{(BR)EBO}		4.0	-	-	Vdc	
Collector Cutoff Current ($V_{CB} = 24 V, I_E = 0$)			ІСВО		_	-	0.5	mAdc	
ON CHARACTERISTICS			•	I		l	-	•	
DC Current Gain (I _C = 100 mA, V _{CE} = 5.0 V)			hFE		15	-	120	-	
DYNAMIC CHARACTERISTICS									
Output Capacitance $(V_{CB} = 28 \text{ V}, I_E = 0, f = 1.0 \text{ MHz})$			C _{ob}		_	-	4.5	pF	
FUNCTIONAL TESTS				•					
Common–Emitter Amplifier Power Gain ($V_{CE} = 23 \text{ V}, P_{out} = 1.5 \text{ W}, f = 470 \text{ MHz}, I_{C} = 200 \text{ mA}$)			GPE		13	-	-	dB	
Saturated Output Power ($V_{CE} = 23 \text{ V}, \text{ f} = 470 \text{ MHz}, \text{ I}_{C} = 200 \text{ mA}$)			P _{sat}		_	2.2	-	w	







C1, C6 — 220 pF 0805 681C Sprague C2 — 8.2 pF ATC100A8R2DP50 C3 — 10 pF ATC100A100DP50 C4, C5 — 27 pF ATC100A8R2DP50 C7 — 10 μ F 35 V C8 — 100 μ F 63 V C9, C10 — 1.0 nF 0805 681C Sprague C11, C12 — 220 pF 0805 681C Sprague L1 — Hairpin wire 1.1 mm L = 33 mm L2 — 4 turns, ID 2.5 mm, 0.5 mm wire ML1 — Microstrip Line W = 2.5 mm Z₀ = 70 Ω , L = 6% λ g at 470 MHz ML2 — Microstrip Line W = 2.5 mm Z₀ = 70 Ω , L = 3% λ g at 470 MHz ML3 — Microstrip Line W = 2.5 mm Z₀ = 70 Ω , L = 5% λ g at 470 MHz ML4 — Microstrip Line W = 2.5 mm Z₀ = 70 Ω , L = 3% λ g at 470 MHz Board Material: 1/16 In. Teflon Glass, ϵ_r = 2.55, h = 1.59 mm Note: λ g is the wavelength in the microstrip circuit



FREQUENCY (MHz)	400	410	420	430	440	450	460	470	480	490	500
RE(Zin)Ω	2.5	2.5	2.5	2.3	2.4	2.3	2.2	2.2	2.1	2.1	2.0
IM(Zin)Ω	2.0	2.2	2.7	3.2	3.5	3.8	3.9	4.0	4.2	4.9	5.0
$RE(Zload)\Omega$	33.4	35.5	36.5	37.0	38.4	39.5	40.4	41.4	42.4	43.4	44.4
IM(Zload)Ω	48.3	48.9	49.4	49.9	50.8	50.9	51.3	51.7	52.2	52.6	53.0

Table 1. Impedance Data V_{CC} = 23 Volts I_C = 200 mA P_{out} = 1.5 Watts

TYPICAL CHARACTERISTICS

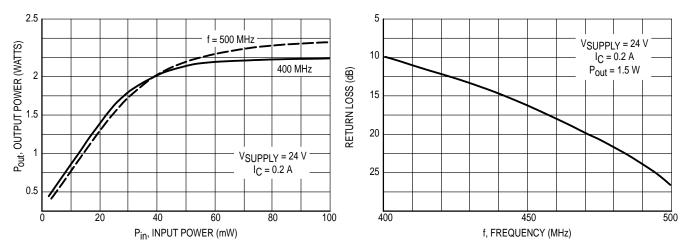




Figure 3. Return Loss versus Frequency

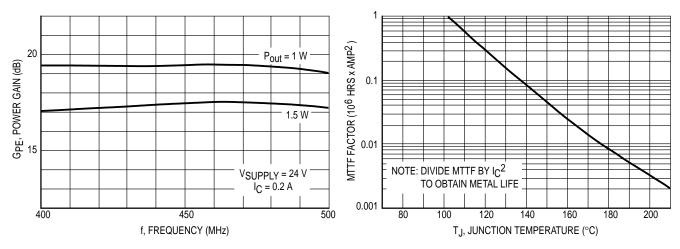


Figure 4. Power Gain versus Frequency



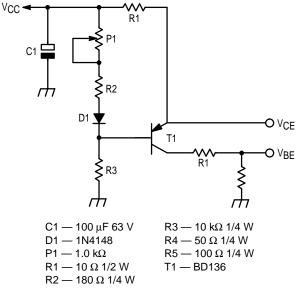
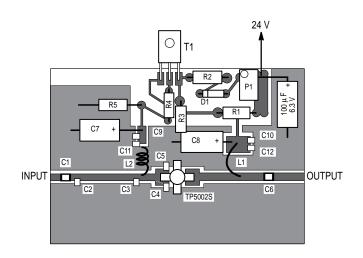
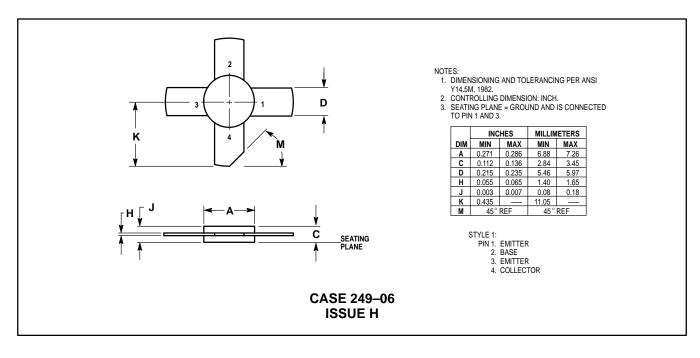


Figure 6. Class A Bias Circuit





PACKAGE DIMENSIONS



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